

BZV85 series Voltage regulator diodes Rev. 03 – 10 November 2009

Product data sheet

Tolerance series: approximately ±5 %

Non-repetitive peak reverse power

dissipation: max. 60 W

1. Product profile

1.1 General description

Medium-power voltage regulator diodes in small hermetically sealed leaded SOD66 (DO-41) glass packages.

The diodes are available in the normalized E24 approximately ± 5 % tolerance range. The series consists of 33 types with nominal working voltages from 3.6 V to 75 V.

1.2 Features

- Total power dissipation: max. 1.3 W
- Working voltage range: nominal 3.3 V to 75 V (E24 range)
- Small hermetically sealed glass package

1.3 Applications

Stabilization purposes

1.4 Quick reference data

Table 1. Quick reference data

	Quion reference auta					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
VF	forward voltage	I _F = 50 mA	-	-	1	V
P _{tot}	total power dissipation					
		$T_{amb} = 25 \ ^{\circ}C;$ lead length 10 mm	<u>[1]</u> _	-	1	W
			[2] _	-	1.3	W
P _{ZSM}	non-repetitive peak reverse power dissipation	square wave; t _p = 100 μs	[3] _	-	60	W

[1] Device mounted on a Printed-Circuit Board (PCB) with 1 cm² copper area per lead.

[2] If the leads are kept at T_{tp} = 55 °C at 4 mm from body.

[3] $T_j = 25 \circ C$ prior to surge



Voltage regulator diodes

2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	cathode	<u>[1]</u>	
2	anode		1 2 006aaa152

[1] The marking band indicates the cathode.

3. Ordering information

Type number	Package	Package				
	Name	Description	Version			
BZV85 series ^[1]	-	hermetically sealed glass package; axial leaded; 2 leads	SOD66			

[1] The series consists of 33 types with nominal working voltages from 3.3 V to 75 V.

4. Marking

Table 4.	Marking codes	
Type num	iber	Marking code
BZV85 se	ries	The diodes are type branded.

5. Limiting values

Symbol	Parameter	Conditions		Min	Max	Unit
l _F	forward current			-	500	mA
IZSM	non-repetitive peak reverse current	square wave; t _p = 100 μs	<u>[1]</u>	-	see <u>Table 8</u>	
		half sine wave; t _p = 10 ms	<u>[1]</u>	-	see <u>Table 8</u>	
P _{tot}	total power dissipation					
		T _{amb} = 25 °C; lead length 10 m m	[2]	-	1	W
			[3]	-	1.3	W
Pzsm	non-repetitive peak reverse power dissipation	square wave; t _p = 100 μs	<u>[1]</u>	-	60	W
Tj	junction temperature			-	200	°C
T _{stg}	storage temperature			-65	+200	°C

[1] $T_j = 25 \ ^{\circ}C$ prior to surge

[2] Device mounted on a PCB with 1 cm^2 copper area per lead.

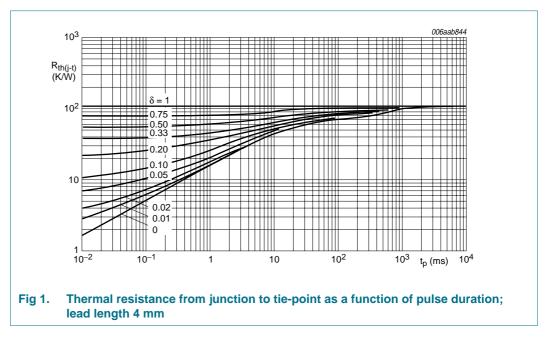
[3] If the leads are kept at T_{tp} = 55 $^\circ C$ at 4 mm from body.

Voltage regulator diodes

6. Thermal characteristics

Table 6.	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-t)}	thermal resistance from junction to tie-point	lead length 4 mm	-	-	110	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	lead length 10 mm	<u>[1]</u> _	-	175	K/W

[1] Device mounted on a PCB with 1 cm² copper area per lead.



7. Characteristics

	Characteristics unless otherwise specifie	d.				
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _F	forward voltage	I _F = 50 mA	-	-	1	V

BZV85 series

Voltage regulator diodes

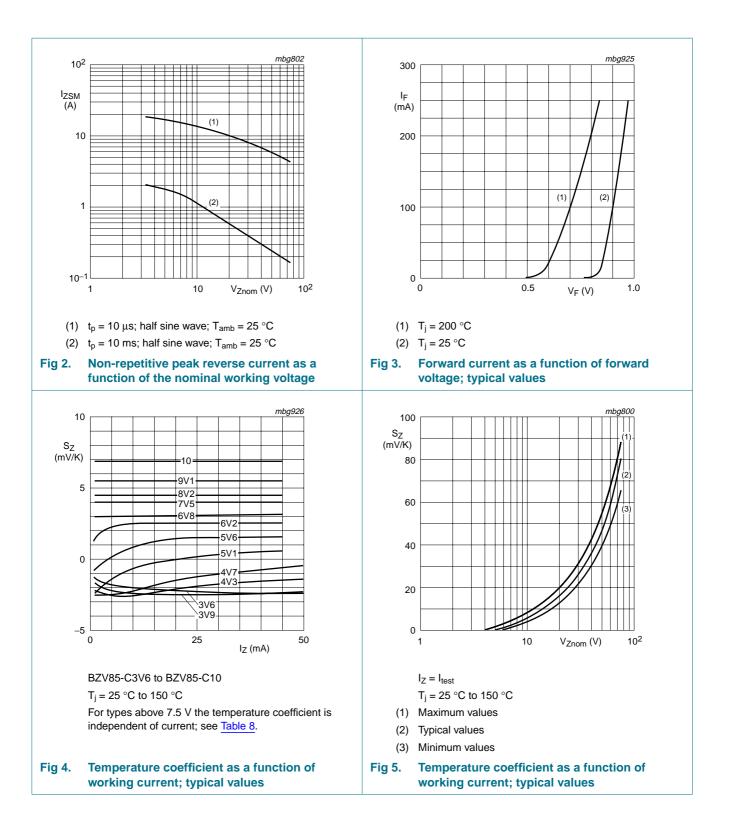
Table 8.	Characteristics per type	è
$T_i = 25 \circ C$	unless otherwise specified	

BZV85- Cxxx	U		oltage resistance c		coefficient curre S ₇ (mV/K) I _{test}		Diode capacitance C _d (pF)	Reverse current I _R (μΑ)		Non-repetitive peak reverse current I _{ZSM}		
	at I _{tes}	t	at I _{test}	at I _{test} (mA)		(IIIA)	at f = 1 MHz; V _R = 0 V			at t _p = 100 μs; T _{amb} = 25 °C	at t _p = 10 ms; T _{amb} = 25 °C	
	Min	Max	Мах	Min	Max		Мах	Max	V _R (V)	Max (A)	Max (mA)	
3V6	3.4	3.8	15	-3.5	-1.0	60	450	50	1.0	8.0	2000	
3V9	3.7	4.1	15	-3.5	-1.0	60	450	10	1.0	8.0	1950	
4V3	4.0	4.6	13	-2.7	0	50	450	5	1.0	8.0	1850	
4V7	4.4	5.0	13	-2.0	0.7	45	300	3	1.0	8.0	1800	
5V1	4.8	5.4	10	-0.5	2.2	45	300	3	2.0	8.0	1750	
5V6	5.2	6.0	7	0	2.7	45	300	2	2.0	8.0	1700	
6V2	5.8	6.6	4	0.6	3.6	35	200	2	3.0	7.0	1620	
6V8	6.4	7.2	3.5	1.3	4.3	35	200	2	4.0	7.0	1550	
7V5	7.0	7.9	3	2.5	5.5	35	150	1	4.5	5.0	1500	
8V2	7.7	8.7	5	3.1	6.1	25	150	0.7	5.0	5.0	1400	
9V1	8.5	9.6	5	3.8	7.2	25	150	0.7	6.5	4.0	1340	
10	9.4	10.6	8	4.7	8.5	25	90	0.2	7.0	4.0	1200	
11	10.4	11.6	10	5.3	9.3	20	85	0.2	7.7	3.0	1100	
12	11.4	12.7	10	6.3	10.8	20	85	0.2	8.4	3.0	1000	
13	12.4	14.1	10	7.4	12.0	20	80	0.2	9.1	3.0	900	
15	13.8	15.6	15	8.9	13.6	15	75	0.05	10.5	2.5	760	
16	15.3	17.1	15	10.7	15.4	15	75	0.05	11.0	1.75	700	
18	16.8	19.1	20	11.8	17.1	15	70	0.05	12.5	1.75	600	
20	18.8	21.2	24	13.6	19.1	10	60	0.05	14.0	1.75	540	
22	20.8	23.3	25	16.6	22.1	10	60	0.05	15.5	1.5	500	
24	22.8	25.6	30	18.3	24.3	10	55	0.05	17	1.5	450	
27	25.1	28.9	40	20.1	27.5	8	50	0.05	19	1.2	400	
30	28.0	32.0	45	22.4	32.0	8	50	0.05	21	1.2	380	
33	31.0	35.0	45	24.8	35.0	8	45	0.05	23	1.0	350	
36	34.0	38.0	50	27.2	39.9	8	45	0.05	25	0.9	320	
39	37.0	41.0	60	29.6	43.0	6	45	0.05	27	0.8	296	
43	40.0	46.0	75	34.0	48.3	6	40	0.05	30	0.7	270	
47	44.0	50.0	100	37.4	52.5	4	40	0.05	33	0.6	246	
51	48.0	54.0	125	40.8	56.5	4	40	0.05	36	0.5	226	
56	52.0	60.0	150	46.8	63.0	4	40	0.05	39	0.4	208	
62	58.0	66.0	175	52.2	72.5	4	35	0.05	43	0.4	186	
68	64.0	72.0	200	60.5	81.0	4	35	0.05	48	0.35	171	
75	70.0	80.0	225	66.5	88.0	4	35	0.05	53	0.3	161	

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8. Package outline

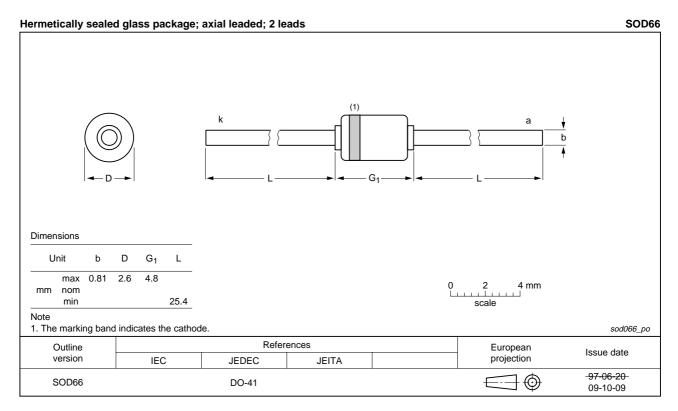


Fig 6. Package outline SOD66 (DO-41)

9. Packing information

Table 9.Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

Type number	Package	Description	Packing quantity
			10000
BZV85 series ^[2] SOD66		52 mm tape ammopack, axial	-133
		52 mm reel pack, axial	-113

[1] For further information and the availability of packing methods, see <u>Section 11</u>.

[2] The series consists of 33 types with nominal working voltages from 3.3 V to 75 V.

10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes				
BZV85_SER_3	20091110	Product data sheet	-	BZV85_2				
Modifications:		t of this data sheet has been of NXP Semiconductors.	redesigned to comply v	vith the new identity				
	 Legal texts 	have been adapted to the n	ew company name whe	ere appropriate.				
	• <u>Table 6</u> : R _t	h(j-tp) redefined to Rth(j-t) therr	nal resistance from june	ction to tie-point				
	• Figure 1: F	 Figure 1: Rth(i-tp) redefined to Rth(i-t) thermal resistance from junction to tie-point 						
	• Table 8 "C	 Table 8 "Characteristics per type": I_{Ztest} redefined to I_{test} test current 						
	 Figure 6 "Package outline SOD66 (DO-41)": updated 							
BZV85_2	19990511	Product specification	-	BZV85_1				
BZV85 1	19960426	Product specification	-	-				

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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13. Contents

1	Product profile 1
1.1	General description
1.2	Features 1
1.3	Applications 1
1.4	Quick reference data 1
2	Pinning information 2
3	Ordering information 2
4	Marking 2
5	Limiting values 3
6	Thermal characteristics 4
7	Characteristics 4
8	Package outline 7
9	Packing information 7
10	Revision history 8
11	Legal information9
11.1	Data sheet status 9
11.2	Definitions
11.3	Disclaimers
11.4	Trademarks
12	Contact information 9
13	Contents 10

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